



## Take advantage of high power & frequencies With PPH15X-20 pHEMT process at attractive price

#### UMS is opening a **PPH15X-20 GaAs process shared foundry run.** The launch date for the Multi-Project Wafer is **October 25, 2024.**

With 800mW/mm power density, **PPH15X-20** high power pHEMT GaAs process allows designers to make High and Medium Power Amplifier MMICs up to 45GHz.

**PPH15X-20** is successfully evaluated for Space use and referenced in the European Preferred Part List by the European Space Agency – see: <u>https://escies.org/epplmanufacturer/show?id=124%20</u>

You can combine in a single integrated amplifier a high output power with a wide frequency range or achieve above 50% power added efficiency on narrow frequency band at an entry price of 2 900€/mm<sup>2</sup>.

### What are the main characteristics of PPH15X-20?

Element	Parameter	Typical value	Conditions			
FET	ldss (mA/mm)	350	Vds = 2.0V, Vgs = 0V			
	Gm (mS/mm)	440	Vds = 2.0V, Vgs = 0V			
	Vbds (V)	14	lds = ldss / 100			
	Vp(V)	-0.95	Vds = 2.0V, Ids = Idss / 100			
	Ft (cut off freq.) (GHz)	70				
MIM Cap.	Density (pF/mm²)	260	@ 1 MHz			
MIM Cap High Density	Density (pF/mm²)	625	@ 1 MHz			
TaN Resistor	Sheet Resistance ( $\Omega/\Box$ )	30				
<b>TiWSi Resistor</b>	Sheet Resistance ( $\Omega/\Box$ )	1000				
GaAs Resistor	Sheet Resistance ( $\Omega/\Box$ )	100				
Wafer thickness	(μm)	70				

# Examples of microwave performance achieved by UMS catalogue MMICs designed on PPH15X-20 process:

Part Number	Freq (GHz)	Gain (dB)	Output Power (dBm/W)	Output IP3 (dBm)	Process					
High power amplifier										
CHA6550-QXG	17-24	22	34 / 2.5	41	PPH15X_20					
CHA6552-QXG	21-27.5	22	34 / 2.5	40	PPH15X_20					
CHA6553-QXG	27.5-33.5	21	32.5/1.8	38	PPH15X_20					
CHA6194-QXG	37-40	20	31/1.2	38	PPH15X_20					

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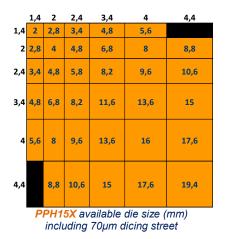


By choosing standard MMIC dimensions which are compatible with QFN high volume packaging capability, your project is on track for future industrial success.



So to start designing, please apply <u>on-line</u> for process Design Kit. Before the deadline, please send your layout to: <u>foundry@ums-rf.com</u>





### How many dies will I receive and how much does it cost?

You will receive 20 dies of your circuit in Gel-Pak® box from a **PPH15X-20** PCM good wafer. The price is based on your circuit dimensions on the mask tile multiplied by the mm<sup>2</sup> unit price. For example, if your circuit is  $1.4 \times 3.4 \text{ mm}^2$ , the price is  $1.4 \times 3.4 \times 2.900 \in = 13.804 \in \mathbb{R}$ .

### Which processes are regularly offered in shared foundry?

	2024							2025					
	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec	Jan	Feb	
GH25 GaN HEMT													
BES Schottky Diode													
GH15 GaN HEMT													
PH25 GaAs Low Noise pHEMT													
PH10 GaAs Low Noise pHEMT													
ULRC Passive													
PPH15X-20 High Power pHEMT													
	Layout submission			Wafer Process				Delivery					

